NSN 5961-01-333-2231

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-333-2231 **Inclosure Material:** Glass **Overall Length:** Between 0.150 inches and 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.068 inches and 0.076 inches **Function For Which Designed:** Detector and mixer and switching **Mounting Method: Terminal Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 8.0 breakdown voltage, dc **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 1.0 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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